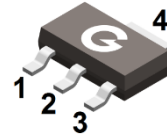
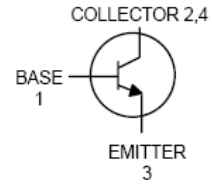


Features

- High collector current
- Low collector-emitter saturation voltage
- RoHS compliant with Halogen-free
- Qualified to AEC-Q101 Standards

HF



SOT-223

Mechanical Data

- Case: SOT-223
- Molding compound: UL flammability classification rating 94V-0
- Terminals: Tin-plated; solderability per MIL-STD-202, Method 208

Ordering Information

Part Number	Package	Shipping Quantity	Marking Code
TBCP56-16	SOT-223	4000 pcs / Tape & Reel	BL

Maximum Ratings (@ T_A = 25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Collector-Base Voltage	V _{CB0}	100	V
Collector-Emitter Voltage	V _{CEO}	80	V
Emitter-Base Voltage	V _{EBO}	5	V
Continuous Collector Current	I _C	1	A
Peak Collector Current (t _p ≤ 1ms)	I _{CM}	2	A
Base Current (Continuous)	I _B	0.1	A
Base Current (Peak)	I _{BM}	0.2	A
Power Dissipation (T _A = 25°C) *1	P _D	2	W
Operating junction Temperature	T _J	-55 ~ +150	°C
Storage Temperature Range	T _{STG}	-55 ~ +150	°C

Thermal Characteristics

Parameter	Symbol	Value	Unit
Thermal Resistance Junction-to-Air *1	R _{θJA}	60	°C/W
Thermal Resistance Junction-to-Case *1	R _{θJC}	25	°C/W
Thermal Resistance Junction-to-Lead *1	R _{θJL}	20	°C/W

Note 1: The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper

Electrical Characteristics (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = 100\mu\text{A}, I_E = 0$	100	-	-	V
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 10\text{mA}, I_B = 0$	80	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = 10\mu\text{A}, I_C = 0$	5	-	-	V
Collector Cut-off Current	I_{CBO}	$V_{CB} = 30\text{V}, I_E = 0$	-	-	100	nA
Emitter Cut-off Current	I_{EBO}	$V_{EB} = 5\text{V}, I_C = 0$	-	-	100	nA
DC Current Gain	h_{FE}	$V_{CE} = 2\text{V}, I_C = 150\text{mA}$	100	-	250	-
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 500\text{mA}, I_B = 50\text{mA}$	-	-	0.5	V
Base-emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = 500\text{mA}, I_B = 50\text{mA}$	-	-	1.2	V
Base-Emitter Voltage	$V_{BE(on)}$	$I_C = 500\text{mA}, V_{CE} = 2\text{V}$	-	-	1	V
Transition Frequency	f_T	$V_{CE} = 10\text{V}, I_C = 50\text{mA}$ $f = 100\text{MHz}$	100	-	-	MHz

Ratings and Characteristic Curves (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

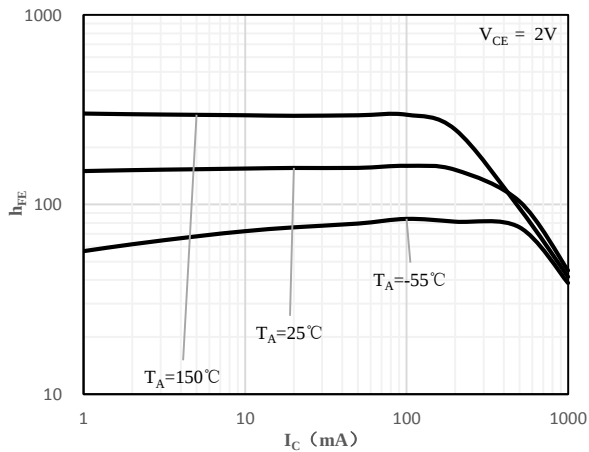


Fig 1 h_{FE} vs. I_C

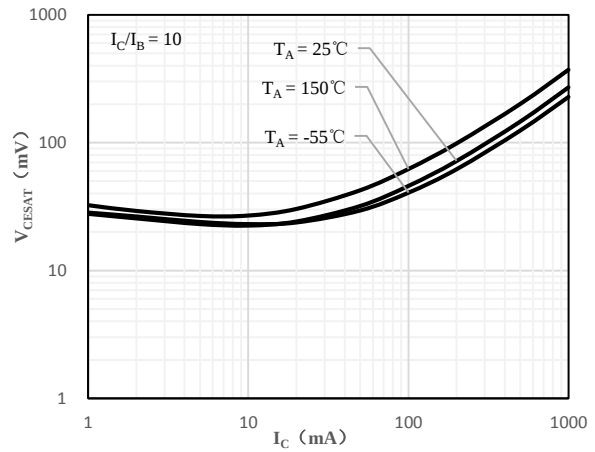


Fig 2 $V_{CE(sat)}$ vs. I_C

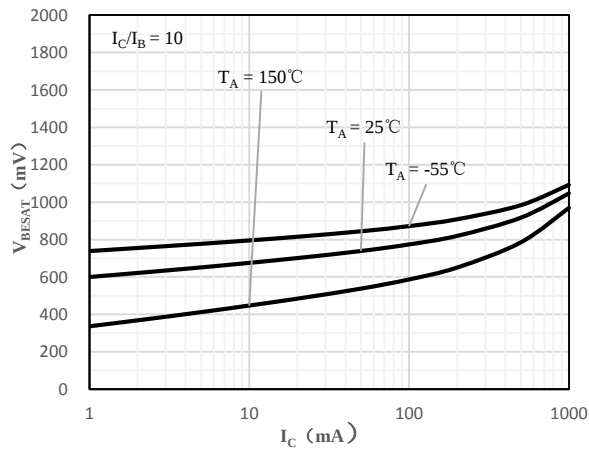


Fig 3 $V_{BE(sat)}$ vs. I_C

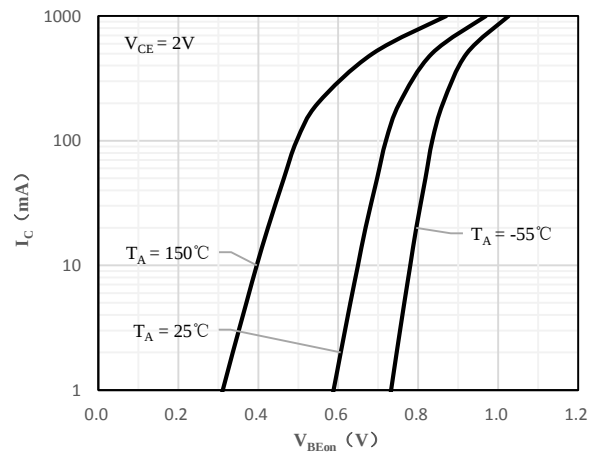


Fig 4 $V_{BE(on)}$ vs. I_C

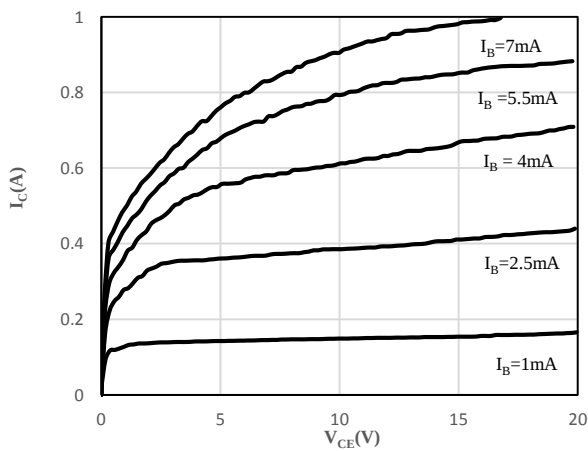


Fig 5 I_C vs. V_{CE}

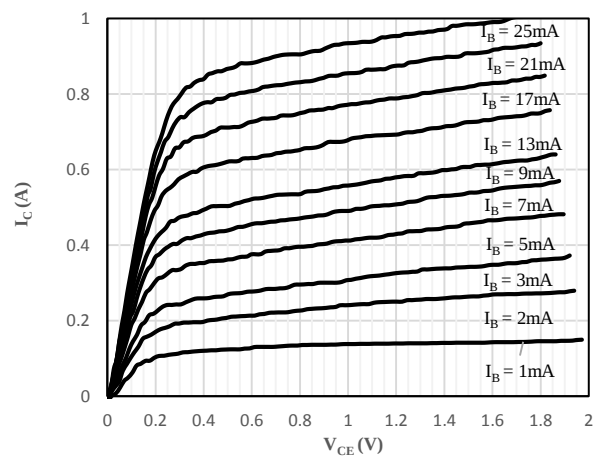


Fig 6 I_C vs. V_{CE}

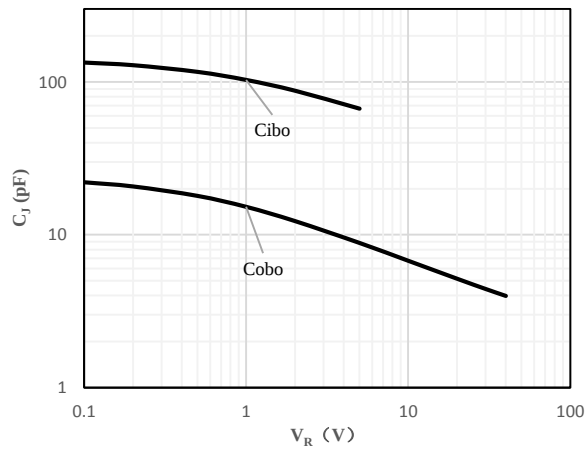


Fig 7 C_j vs. V_R

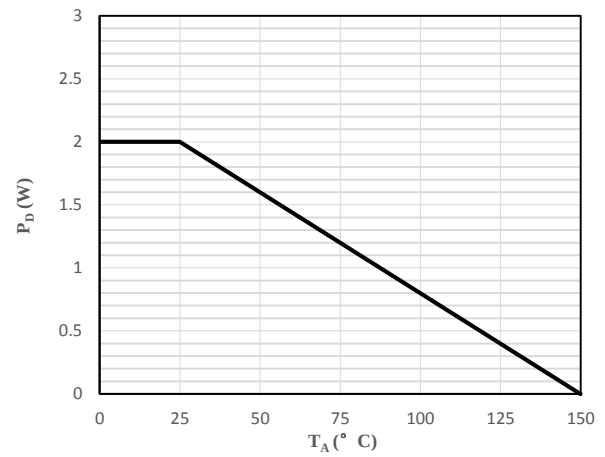


Fig 8 P_D vs. T_A

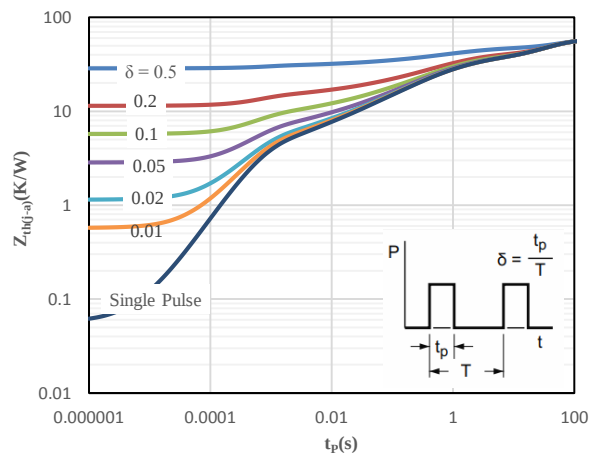
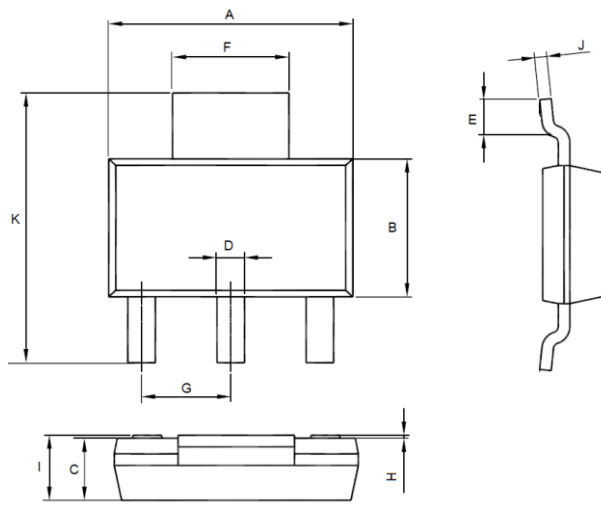


Fig 9 Maximum transient thermal impedance

Package Outline Dimensions (Unit: mm)



SOT-223		
Dimension	Min.	Max.
A	6.10	6.50
B	3.30	3.70
C	1.50	1.70
D	0.66	0.82
E	0.90	1.15
F	2.90	3.10
G	2.20	2.40
H	0.02	0.10
I	1.52	1.80
J	0.20	0.40
K	6.70	7.30

Mounting Pad Layout (Unit: mm)

SOT-223

